2SD2222

Silicon NPN triple diffusion planar type Darlington

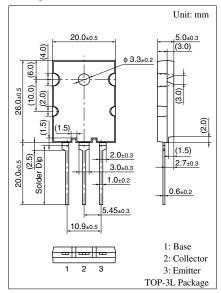
For power amplification Complementary to 2SB1470

■ Features

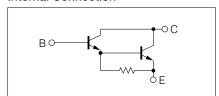
- Optimum for 120 W Hi-Fi output
- High forward current transfer ratio h_{FE}
- \bullet Low collector to emitter saturation voltage $V_{\text{CE}(\text{sat})}$

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base voltage		V_{CBO}	160	V
Collector to emitter voltage		V_{CEO}	160	V
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	15	A
Collector current		I_C	8	A
Collector power	$T_C = 25^{\circ}C$	$P_{\rm C}$	150	W
dissipation	$T_a = 25^{\circ}C$		3.5	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C



Internal Connection



■ Electrical Characteristics $T_C = 25$ °C

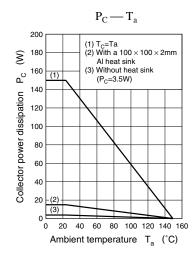
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 160 \text{ V}, I_E = 0$			100	μΑ
	I_{CEO}	$V_{CE} = 160 \text{ V}, I_{B} = 0$			100	μΑ
Emitter cutoff current	I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			100	μΑ
Collector to emitter voltage	V_{CEO}	$I_{\rm C} = 30 \text{ mA}, I_{\rm B} = 0$	160			V
Forward current transfer ratio	h _{FE1}	$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ A}$	10 000			
	h _{FE2} *	$V_{CE} = 5 \text{ V}, I_{C} = 7 \text{ A}$	3 500		20 000	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 7 \text{ A}, I_{\rm B} = 7 \text{ mA}$			3	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 7 \text{ A}, I_{\rm B} = 7 \text{ mA}$			3	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_C = 7 \text{ A}, I_{B1} = 7 \text{ mA}, I_{B2} = -7 \text{ mA},$		2		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		6		μs
Fall time	t_{f}			1.2		μs

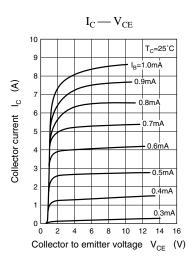
Note) *: Rank classification

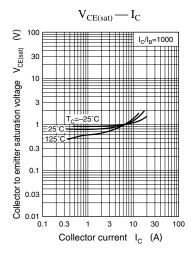
Rank	Q	Р			
h _{FE2}	3 500 to 10 000	7 000 to 20 000			

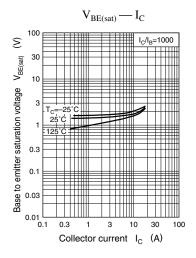
Panasonic 1

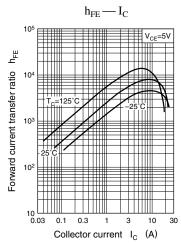
2SD2222 Power Transistors

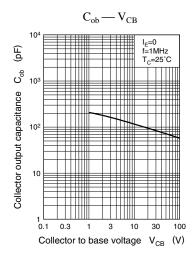


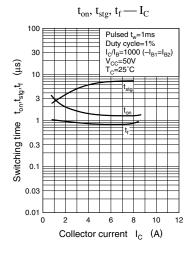


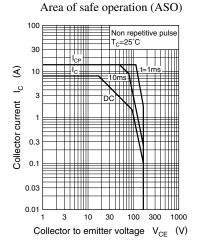




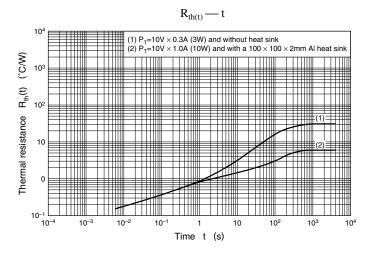








Power Transistors 2SD2222



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